

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Application for:

**Bernard Beaumont, et al.**

Serial No. 10/522,397

Filed: October 21, 2005

For: METHOD FOR PRODUCING BY  
VAPOUR-PHASE EPITAXY A GALLIUM  
NITRIDE FILM WITH LOW DEFECT DENSITY

Examiner: Marissa W. Chaet

Art Unit: 1722

Confirmation No.: 6314

**AMENDMENT AND RESPONSE TO OFFICE ACTION**

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Madam :

In response to the Office Action dated July 10, 2007 please amend the above-captioned application as set forth below.

**Amendments to the Claims** are reflected in the listing of claims and begins on page 2 of this paper.

**Remarks/Arguments** begin on page 6 of this paper.